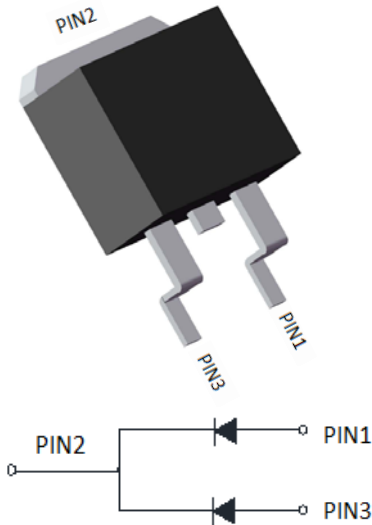


Schottky Diodes



Features

- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260°C

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-263
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBRBL3045CT
Device marking code			MBRBL3045CT
Repetitive Peak Reverse Voltage	V_{RRM}	V	45
Average Rectified Output Current @60Hz sine wave, R-load, Ta (FIG 1)	I_o	A	30
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, Ta=25°C	I_{FSM}	A	250
Current Squared Time @1ms≤t≤8.3ms Tj=25°C, rating of per diode	I^2t	A ² s	259
Storage Temperature	T_{stg}	°C	-55 ~ +150
Junction Temperature	T_j	°C	-55 ~ +150

■Electrical Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBRBL3045CT
Maximum instantaneous forward voltage drop per diode	V_{FM}	V	$I_{FM}=15.0A$	0.55
Maximum DC reverse current at rated DC blocking voltage per diode	I_{RRM1}	mA	$V_{RM}=V_{RRM}$ $T_a=25^\circ C$	0.2
	I_{RRM2}		$V_{RM}=V_{RRM}$ $T_a=100^\circ C$	50

Note1:Pulse test:300uS pulse width,1% duty cycle

Note2:Pulse test:pulse width 40mS



MBRBL3045CT

■ Thermal Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MBRBL3045CT
Thermal Resistance	Between junction and case	R _{θJ-C}	°C/W	2.0

■ Ordering Information (Example)

PREFERRED P/N	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBRBL3045CT	Approximate 1.43	50	2000	8000	Tube
MBRBL3045CT	Approximate 1.43	1000	2000	10000	Reel

■ Characteristics (Typical)

FIG1: I_o -T_c Curve

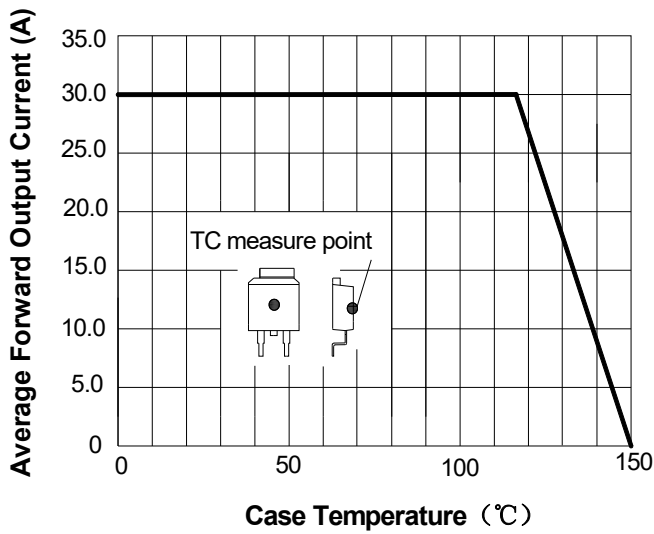


FIG2: Surge Forward Current Capability

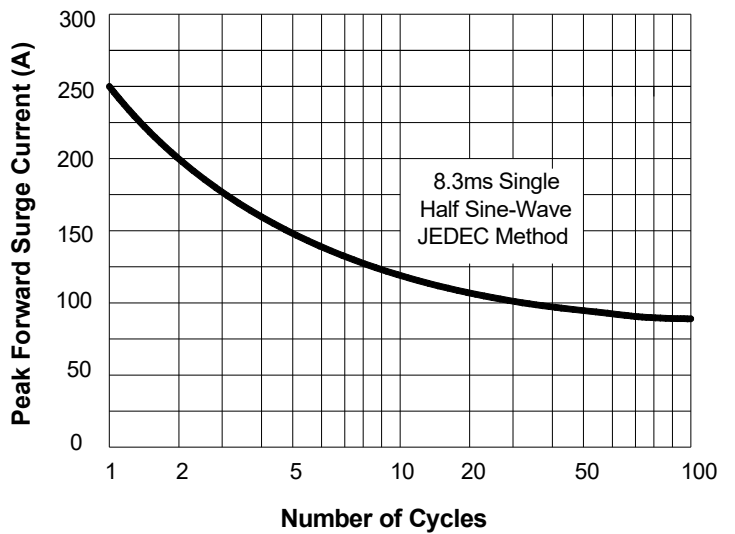


FIG3: Forward Voltage

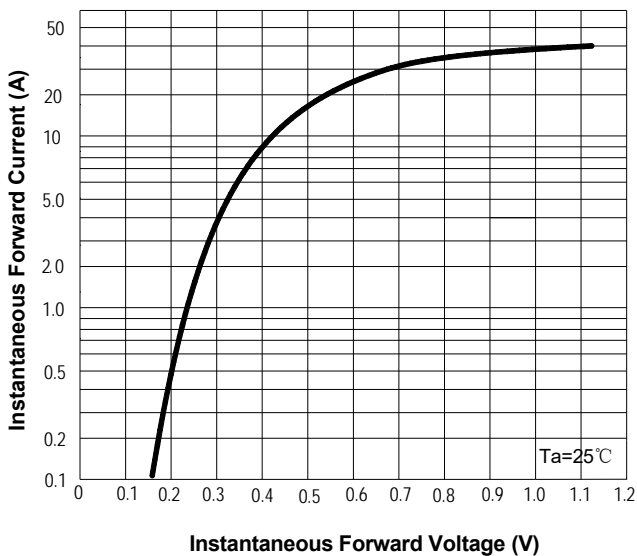
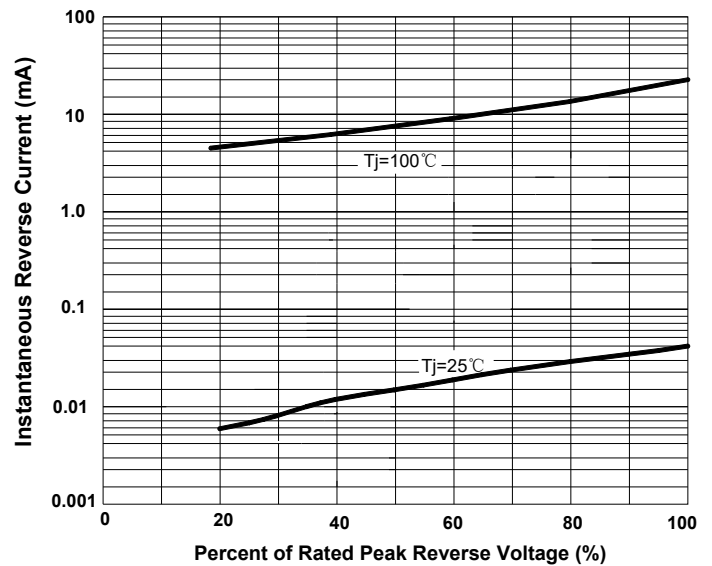


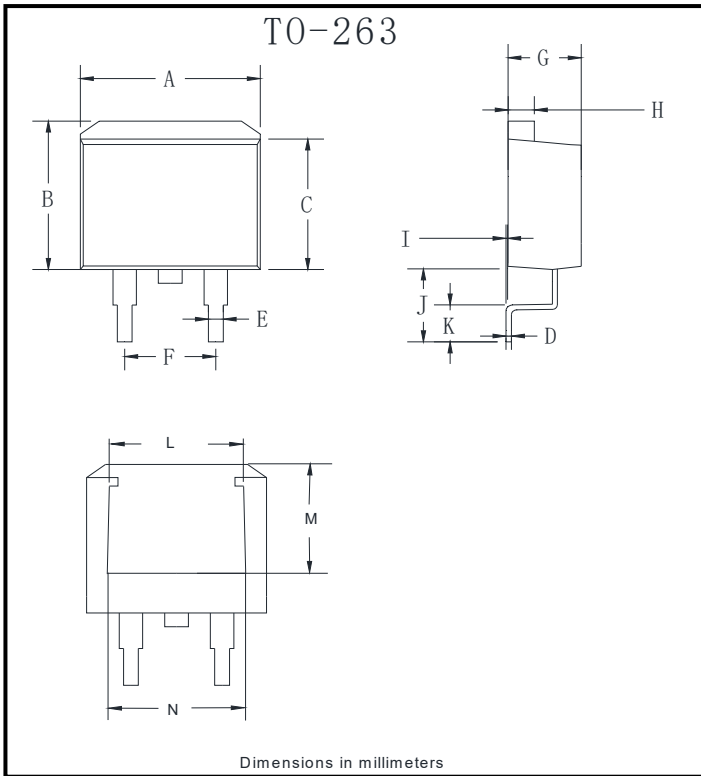
FIG4: Typical Reverse Characteristics





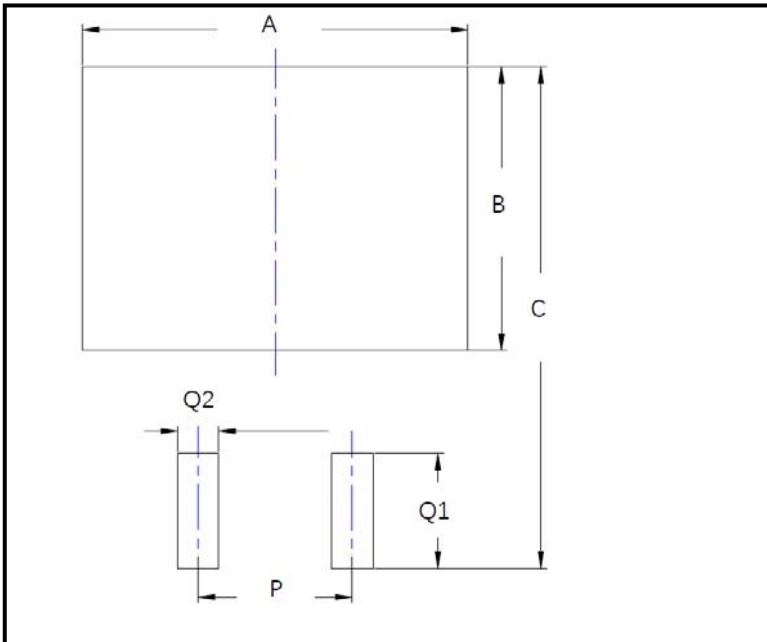
MBRBL3045CT

■ Outline Dimensions



TO-263		
Dim	Min	Max
A	9.5	11.5
B	9.7	10.5
C	8.4	9.0
D	0.28	0.64
E	0.68	0.94
F	4.55	5.6
G	4.04	5.10
H	1.14	1.4
I	0	0.2
J	4.9	6.05
K	1.79	2.79
L	7.3	7.9
M	6.2	6.8
N	7.6	8.2

■ Suggested Pad Layout



Dim	Millimeters
A	12.7
B	9.4
C	16.6
P	5.08
Q1	3.8
Q2	1.35



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